MSKSEMI 美森科















ESD

MOV

MMAX811X

产品手册





产品简介

MMAX811X系列是一款具有电压检测功能的微处理器复位芯片,它带有使能控制端,用于监控微控制器或其他逻辑系统的电源电压。

它可以在上电掉电和节电情况下,或在电源电压低于预设的检测电压 V_{th} 时,向系统提供复位信号。同时,在上电或电源电压恢复到高于预设的检测电压 V_{th} 时,或使能 \overline{MR} 电压由低电平变为高电平时, V_{RESET} 输出将延时 T_{rp} 时间后输出变为高电平。

MMAX811X系列芯片当输入电压低于检测电压Vth 时序VET 输出为低电平;当使能控制端 MR 电压为低电平时,VRESET 输出也为低电平。应用简单,无需外部器件。

产品特点

- 低功耗: 2uA (典型值) @VMR =VCC
- 具有VCC 瞬态抗干扰
- 应用简单,无需外部元件
- 内置复位延时时间500ms (典型值)
- 高精度复位电压值: ±2.5%
- 具有使能控制端MR,低电平有效
- 小体积封装: SOT-143

产品用途

- 电池供电设备
- 掉电检测器
- 电脑、微机处理器
- 非易失性 RAM 信号存储保护器
- 临界 MP 电源监控
- 嵌入式系统

封装形式和管脚

封装形式	管脚定义		
MERELY I	VCC MR 3 1 2 GND RESET		
SOT-143			

管脚序号 SOT-143	管脚定义	功能说明
1	GND	电源负极端
2	RESET	复位输出端
3	MR	使能控制端
4	VCC	电源正极端



型号和丝印详情

名称	型号	最高输入电压 VCC (V)	复位电压Vth (V)	Vth 容差	封装形式
	MMAX811L	6.0	4.63	<u>+</u> 2.5%	
	MMAX811M	6.0	4.38	<u>+</u> 2.5%	
MMAX811	MMAX811J	6.0	4.00	<u>+</u> 2.5%	SOT-143
	MMAX811T	6.0	3.08	<u>+</u> 2.5%	
	MMAX811S	6.0	2.93	<u>+</u> 2.5%	
	MMAX811R	6.0	2.63	+2.5%	

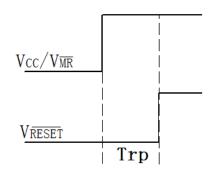
MMAX811L	MMAX811M MMAX811J		
AMAA	ANAA	AOAA	
MMAX811T	MMAX811S	MMAX811R	
APAA	AQAA	ARAA	



应用电路

VCC O VCC PROCESSOR RESET INPUT GND GND GND GND

上电复位时间



极限参数

项目	符号	说明 极限值		单位
4 5	V _{cc}	输入电压	6.5	V
电 压	电压 V _{RESET} 复位输出电压 -(-0.3∼ Vcc+0.3	٧
功耗	PD	SOT143	200	mW
	T_{A}	工作温度范围	-20—70 °C	
温度 T _S 存储温度范围		-50—125	C	
	Tw	焊接温度	260	℃,10s

电学特性

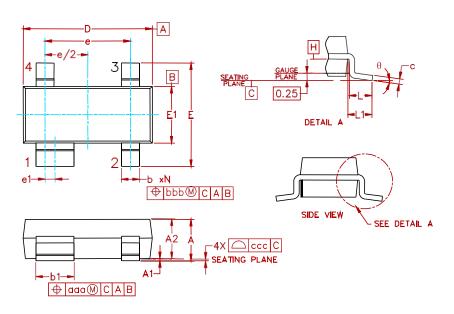
MMAX811X

(Ta=25℃,除非特别指定)

符号	参数	测试条件		最小	典型	最大	单位
V_{CC}	工作电压			1.0	1	6.0	V
$V_{\sf th}$	输入检测电压	V _{CC} =V _{th} for V _{RESET} =H→L	, No Load	0.975*V _{th}	$V_{\sf th}$	1.025*V _{th}	V
I_{CCH}	静态电流	V _{CC} =6V, V _{MR} =VCC, No Load	[1	I	5	uA
I_{CCL}	待机电流	V _{CC} =6V, V _{MR} =GND, No Load	[1	I	32	uA
I_{MR}	使能拉电流	V _{CC} =6V, V _{MR} =GND, No Load	[1	I	25	uA
$T_{\sf rd}$	复位下降沿时间	$V_{CC} = V_{th}$ to $V_{th} - 100 \text{mV}$		-	150	I	ns
	MAX811Z/R/S/T:						
		$V_{CC}=V_{MR}=0$ to 3.5V or	No Load	85	500	900	me
т	T _{rp} 输出复位时间	$V_{MR} = 0 \text{ to } 3.5 \text{ V}, V_{CC} = 3.5 \text{ V}$					
¹rp		MAX811M/L:	NO LOAU 65		300	300	ms
		$V_{CC}=V_{MR}=0$ to 5V or					
		V_{MR} =0 to 5V, V_{CC} =5V					
V_{OL}	输出低电压	$V_{\text{CC}} = V_{\text{th}} \text{min}$, $I_{\text{SINK}} = 3.2 \text{mA}$		-	-	0.5	V
V_{OH}	输出高电压	$V_{CC} > V_{th} max$, $I_{SOURCE} = 500 uA$		0.8V _{cc}	П	=	V
V_{MRH}	输入高电平	V _{CC} =6V, V _{RESET} =V _{CC} , No Load		0.7* V _{CC}	-	V_{CC}	V
V_{MRL}	输入低电平	V _{CC} =6V, V _{RESET} =GND, No Load		0	I	0.2*V _{CC}	V
t_{MR}	使能电平最小脉宽			10	ı	-	us
∆ Vth				±200		ppm/	
Vth∗ △ Ta	皿/又尔奴	20 C < 1a < 00 C	-20°C≤Ta≤60°C		±200		$^{\circ}$

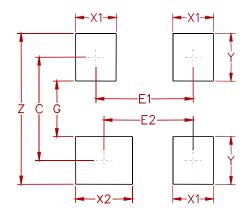


封装信息



		Inches		NA:	II: 4 .	
Symbol				Millimete		
	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	0.031	-	0.048	0.80	-	1.22
A 1	0.000	-	0.008	0.013	-	0.15
A2	0.020	0.035	0.042	0.75	0.90	1.07
b	0.011	-	0.020	0.30	-	0.51
b1	0.029	-	0.037	0.76	-	0.94
С	0.003	-	0.008	0.08	-	0.20
D	0.110	0.114	0.120	2.80	2.90	3.04
E	0.082	0.093	0.104	2.10	2.37	2.64
E1	0.047	0.051	0.055	1.20	1.30	1.40
е	0.075			1.92 BSC		
e1		0.008		0.20 BSC		
L	0.015	0.020	0.024	0.40	0.50	0.60
L1	(0.021)				(0.54)	
N	4				4	
θ	0°	-	8°	0°	-	8°
aaa	0.006			0.15		
bbb	0.008				0.20	
ССС	0.004 0.10					

焊盘布局



订购信息

P/N	PKG	QTY
MMAX811	SOT-143	3000



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